查询SN54BCT240供应商

捷多邦,专业PCB打样SN54B0币240,出SN74BCT240 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SCBS004E - OCTOBER 1987 - REVISED APRIL 1994

- State-of-the-Art BiCMOS Design Significantly Reduces I_{CCZ}
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Package Options Include Plastic Small-Outline (DW) and Shrink Small-Outline (DB) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic and Ceramic 300-mil DIPs (J, N)

description

These octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. Taken together with the 'BCT241 and 'BCT244, these devices provide the choice of selected combinations of inverting and noninverting outputs, symmetrical OE (active-low output-enable) inputs, and complementary OE and OE inputs. These devices feature high fan-out and improved fan-in.

The 'BCT240 is organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

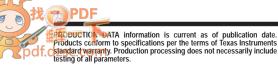
The SN54BCT240 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74BCT240 is characterized for operation from 0°C to 70°C.

SN54BCT240 J OR W PACKAGE SN74BCT240 DB, DW OR N PACKAGE (TOP VIEW)									
1OE 1 20 V _{CC} 1A1 2 19 2OE 2Y4 3 18 1Y1 1A2 4 17 2A4 2Y3 5 16 1Y2 1A3 6 15 2A3 2Y2 7 14 1Y3 1A4 8 13 2A2 2Y1 9 12 1Y4 GND 10 11 2A1									

SN54BCT240 ... FK PACKAGE (TOP VIEW)

	2Υ4	CC 10E	2 <u>0</u> E	
1A2 2Y3 1A3 2Y2 1A4	3 4 5 6 7 8 9		18 17 16 15 14	1Y1 2A4 1Y2 2A3 1Y3
	2Y1	2A1 1Y4	2A2	

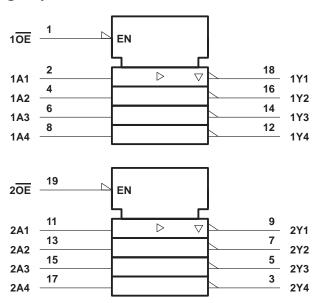
FUNCTION TABLE (each buffer)							
INPUTS OUTPUT							
OE	Α	Y					
L	Н	V L					
L	L	Н					
H	Х	Z					



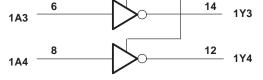


SN54BCT240, SN74BCT240 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SCBS004E – OCTOBER 1987 – REVISED APRIL 1994

logic symbol[†]

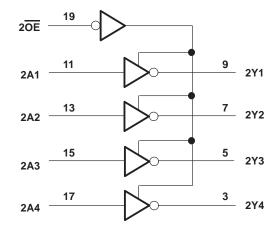


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



1Y1

1Y2



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1)		
Voltage range applied to any output in th		
Voltage range applied to any output in th		
Input clamp current, IIK		
Current into any output in the low state:	SN54BCT240	
	SN74BCT240	128 mA
Operating free-air temperature range:	SN54BCT240	– 55°C to 125°C
	SN74BCT240	0°C to 70°C
Storage temperature range		– 65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



SN54BCT240, SN74BCT240 **OCTAL BUFFERS/DRIVERS** WITH 3-STATE OUTPUTS SCBS004E – OCTOBER 1987 – REVISED APRIL 1994

recommended operating conditions

		SN54BCT240			SN74BCT240			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
Iк	Input clamp current	-18		-18	mA			
ЮН	High-level output current	-12				-15	mA	
IOL	Low-level output current	48				64	mA	
TA	Operating free-air temperature	-55 125		0		70	°C	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED			SN	N54BCT240 SN74BCT240		SN74BCT240			
PARAMETER		TEST CONDITIONS		түр†	MAX	MIN	түр†	MAX	UNIT
VIK	V _{CC} = 4.5 V,	lı = -18 mA			-1.2			-1.2	V
		I _{OH} = -3 mA	2.4	3.3		2.4	3.3		
VOH	$V_{CC} = 4.5 V$	I _{OH} = -12 mA	2	3.2					V
		I _{OH} = -15 mA				2	3.1		
Ve		I _{OL} = 48 mA		0.38	0.55				V
VOL	V_{OL} $V_{CC} = 4.5 V$	I _{OL} = 64 mA					0.42	0.55	v
Ц	V _{CC} = 5.5 V,	V _I = 7 V			0.1			0.1	mA
Iн	V _{CC} = 5.5 V,	V _I = 2.7 V			20			20	μΑ
١ _{IL}	V _{CC} = 5.5 V,	V _I = 0.5 V			-1			-1	mA
IOZH	V _{CC} = 5.5 V,	V _O = 2.7 V			50			50	μΑ
IOZL	V _{CC} = 5.5 V,	V _O = 0.5 V			-50			-50	μΑ
los‡	V _{CC} = 5.5 V,	$V_{O} = 0$	-100		-225	-100		-225	mA
ІССН	V _{CC} = 5.5 V,	Outputs open		19	31		19	31	mA
ICCL	V _{CC} = 5.5 V,	Outputs open		46	71		46	71	mA
Iccz	V _{CC} = 5.5 V,	Outputs open		6	9		6	9	mA
Ci	V _{CC} = 5 V,	VI = 2.5 V or 0.5 V		6			6		pF
Co	V _{CC} = 5 V,	V _O = 2.5 V or 0.5 V		11			11		pF

[†] All typical values are at V_{CC} = 5 V.
[‡] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.



switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CI R´ R:	CC = 5 V = 50 p 1 = 500 9 2 = 500 9 4 = 25°C	F , Ω, Ω,	CL R1 R2	= 50 pl = 500 0 = 500 0	2,	V,	UNIT
			΄l	BCT240		SN54B	CT240	SN74B	CT240	
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
^t PLH	٨	Y	0.5	3.3	4.8	0.5	6.4	0.5	5.6	ns
^t PHL	A	T	0.4	1.8	3.5	0.4	4.5	0.4	4	115
^t PZH	ŌĒ	Y	1	6.4	7.9	1	9.2	1	8.8	ns
^t PZL	ÛE	T	1	7.5	9.4	1	10.8	1	10.5	115
^t PHZ	OE	Y	1	6	6.8	1	8.5	1	8.1	ns
tPLZ		I I	1	6.7	8.1	1	10.6	1	9.5	115

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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